

HALF-BRIDGE DRIVER

Features

- Floating channel designed for bootstrap operation Fully operational to +600V
 Tolerant to negative transient voltage dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout for both channels
- 3.3V, 5V and 15V input logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- High side output in phase with IN input
- Logic and power ground +/- 5V offset.
- Internal 500ns dead-time, and programmable up to 5us with one external R_{DT} resistor
- Lower di/dt gate driver for better noise immunity
- The dual function DT/SD pin input turns off both channels.
- Available in Lead-Free

Description

The IR21091(S) are high voltage, high speed power MOSFET and IGBT drivers with dependant high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable rugge-

Product Summary

VOFFSET 600V max.

I_{O+}/- 120 mA / 250 mA

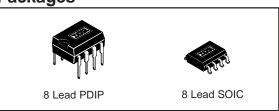
VOUT 10 - 20V

ton/off (typ.) 680 & 170 ns

Dead time 500 ns

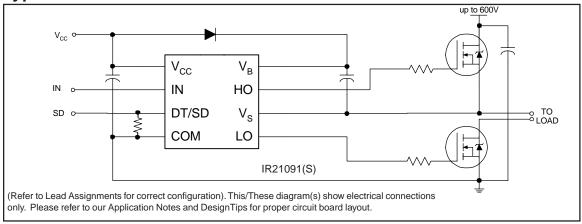
(programmable up to 5uS)

Packages



dized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 volts.

Typical Connection



International

TOR Rectifier

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

| Symbol | Definition | | Min. | Max. | Units |
|---------------------|--|--|-----------------------|-----------------------|-------|
| V _B | High side floating absolute voltage | | -0.3 | 625 | |
| Vs | High side floating supply offset voltage | gh side floating supply offset voltage | | V _B + 0.3 | |
| V _{HO} | High side floating output voltage | | V _S - 0.3 | V _B + 0.3 | |
| V _{CC} | Low side and logic fixed supply voltage | | -0.3 | 25 |] , |
| V _{LO} | Low side output voltage | | -0.3 | V _{CC} + 0.3 | V |
| DT/SD | Programmable dead-time and shut-down pin voltage | | V _{SS} - 0.3 | V _{CC} + 0.3 | |
| V _{IN} | Logic input voltage | | V _{SS} - 0.3 | V _{CC} + 0.3 | |
| dV _S /dt | Allowable offset supply voltage transient | | _ | 50 | V/ns |
| PD | Package power dissipation @ T _A ≤ +25°C | (8 Lead PDIP) | _ | 1.0 | |
| | | (8 Lead SOIC) | _ | 0.625 | W |
| Rth _{JA} | Thermal resistance, junction to ambient | (8 Lead PDIP) | _ | 125 | 00/// |
| | | (8 Lead SOIC) | _ | 200 | °C/W |
| TJ | Junction temperature | | _ | 150 | |
| T _S | Storage temperature | | -50 | 150 | °C |
| TL | Lead temperature (soldering, 10 seconds) | | _ | 300 | |

Recommended Operating Conditions

The input/output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating are tested with all supplies biased at 15V differential.

| Symbol | Definition | Min. | Max. | Units |
|-----------------|--|---------------------|---------------------|-------|
| VB | High side floating supply absolute voltage | V _S + 10 | V _S + 20 | |
| Vs | High side floating supply offset voltage | Note 1 | 600 | |
| VHO | High side floating output voltage | Vs | V _B | |
| Vcc | Low side and logic fixed supply voltage | 10 | 20 | V |
| V _{LO} | Low side output voltage | 0 | Vcc | · |
| VIN | Logic input voltage | V _{SS} | Vcc | |
| DT/SD | Programmable dead-time and shut-down pin voltage | V _{SS} | Vcc | |
| TA | Ambient temperature | -40 | 125 | °C |

Note 1: Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to -V_{BS}. (Please refer to the Design Tip DT97-3 for more details).

Dynamic Electrical Characteristics

 V_{BIAS} (V_{CC} , V_{BS}) = 15V, C_L = 1000 pF, T_A = 25°C, DT = VSS unless otherwise specified.

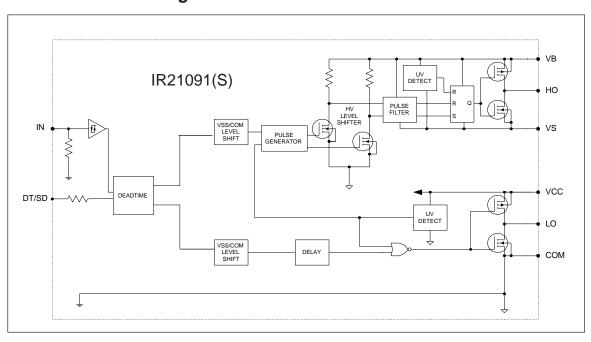
| Symbol | Definition | Min. | Тур. | Max. | Units | Test Conditions |
|----------------|--|------|------|------|-------|-----------------------------|
| ton | Turn-on propagation delay | _ | 750 | 950 | | V _S = 0V |
| toff | Turn-off propagation delay | _ | 200 | 280 | | V _S = 0V or 600V |
| MT | Delay matching, HS & LS turn-on/off | _ | 0 | 70 | | |
| t _r | Turn-on rise time | _ | 150 | 220 | nsec | V _S = 0V |
| tf | Turn-off fall time | _ | 50 | 80 | | V _S = 0V |
| DT | Deadtime: LO turn-off to HO turn-on(DTLO-HO) & | 400 | 540 | 680 | | RDT= 0 |
| | HO turn-off to LO turn-on (DTHO-LO) | 4 | 5 | 6 | usec | RDT = 200k |
| MDT | Deadtime matching = DTLO - HO - DTHO-LO | | 0 | 60 | | RDT=0 |
| | | | 0 | 600 | nsec | RDT = 200k |
| tsd | Shut down propagation delay | 215 | _ | 615 | | |

Static Electrical Characteristics

 V_{BIAS} (V_{CC} , V_{BS}) = 15V, DT= V_{SS} and T_A = 25°C unless otherwise specified. The V_{IL} , V_{IH} and I_{IN} parameters are referenced to V_{SS} /COM and are applicable to the respective input leads: IN and DT. The V_O , I_O and Ron parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

| Symbol | Definition | Min. | Тур. | Max. | Units | Test Conditions |
|---------------------|--|------|------|------|-------|--------------------------------|
| V _{IH} | Logic "1" input voltage for HO & logic "0" for LO | 2.9 | _ | _ | | V _{CC} = 10V to 20V |
| V _{IL} | Logic "0" input voltage for HO & logic "1" for LO | _ | _ | 0.8 | | V _{CC} = 10V to 20V |
| V _{SD,TH} | DT/SD pin shutdown input threshold | 11.5 | 13 | 14.5 | ., | |
| VoH | High level output voltage, V _{BIAS} - V _O | _ | 0.8 | 1.4 | V | I _O = 20 mA |
| V _{OL} | Low level output voltage, VO | _ | 0.3 | 0.6 | | I _O = 20 mA |
| I _{LK} | Offset supply leakage current | _ | _ | 50 | μA | $V_{B} = V_{S} = 600V$ |
| I _{QBS} | Quiescent V _{BS} supply current | 20 | 60 | 150 | μΛ | V _{IN} = 0V or 5V |
| IQCC | Quiescent V _{CC} supply current | 0.4 | 1.0 | 1.6 | mA | V _{IN} = 0V or 5V |
| | | | | | | RDT = 0 |
| I _{IN+} | Logic "1" input bias current | _ | 5 | 20 | μA | IN = 5V, SD = 0V |
| I _{IN-} | Logic "0" input bias current | _ | 1 | 2 | μΛ | $IN = 0V, \overline{SD} = 5V$ |
| V _{CCUV+} | V _{CC} and V _{BS} supply undervoltage positive going | 8.0 | 8.9 | 9.8 | | |
| V _{BSUV+} | threshold | | | | | |
| V _{CCUV} - | V _{CC} and V _{BS} supply undervoltage negative going | 7.4 | 8.2 | 9.0 | V | |
| V _{BSUV} - | threshold | | | | • | |
| Vccuvh | Hysteresis | 0.3 | 0.7 | _ | | |
| V _{BSUVH} | | | | | | |
| I _{O+} | Output high short circuit pulsed vurrent | 120 | 200 | _ | ^ | $V_O = 0V$, $PW \le 10 \mu s$ |
| I _O - | Output low short circuit pulsed current | 250 | 350 | _ | mA | V _O =15V,PW ≤ 10 μs |

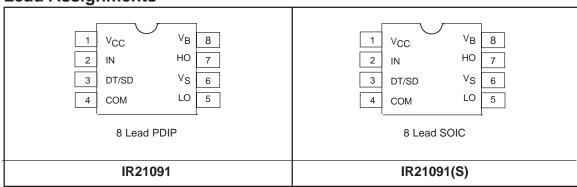
Functional Block Diagrams



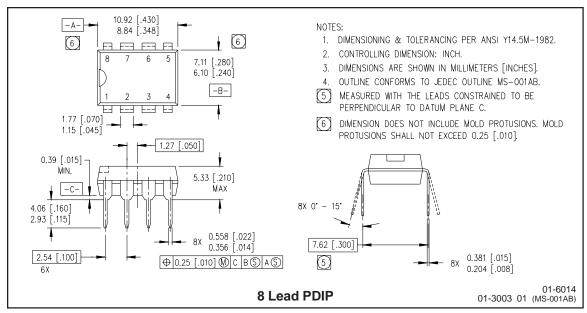
Lead Definitions

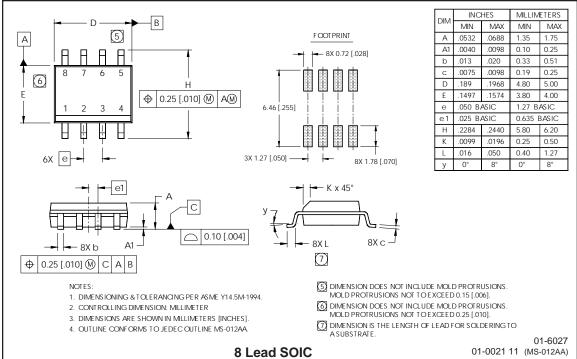
| Symbol | Description |
|----------------|--|
| IN | Logic input for high and low side gate driver outputs (HO and LO), in phase with HO |
| DT/SD | Programmable dead-time lead, referenced to VSS. Disables input/output logic when tied to VCC |
| V _B | High side floating supply |
| НО | High side gate drive output |
| Vs | High side floating supply return |
| Vcc | Low side and logic fixed supply |
| LO | Low side gate drive output |
| COM | Low side return |

Lead Assignments



Case Outlines





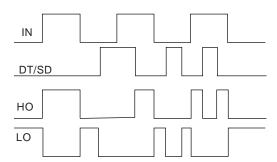


Figure 1. Input/Output Timing Diagram

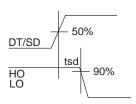


Figure 3. Shutdown Waveform Definitions

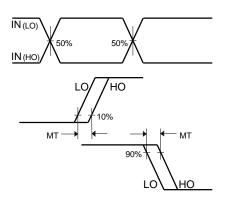


Figure 5. Delay Matching Waveform Definitions

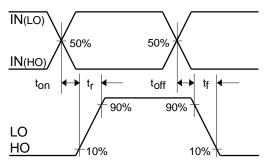


Figure 2. Switching Time Waveform Definitions

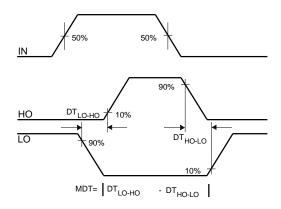
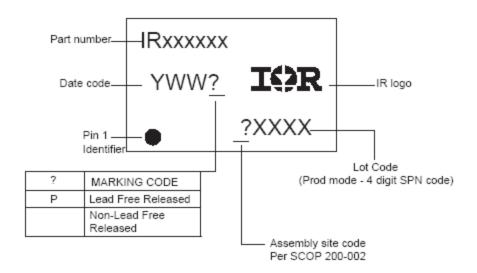


Figure 4. Deadtime Waveform Definitions

LEADFREE PART MARKING INFORMATION



Basic Part (Non-Lead Free)

Lead-Free Part

8-Lead PDIP IR21091 order IR21091 8-Lead SOIC IR21091S order IR21091S 8-Lead PDIP IR21091 order IR21091PBF 8-Lead SOIC IR21091S order IR21091SPBF



This product has been designed and qualified for the Industrial market.

Qualification Standards can be found on IR's Website.

Data and specifications subject to change without notice.

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105

TAC Fax: (310) 252-7903

Visit us at www.irf.com for sales contact information. 7/19/2005